SN5413, SN54LS13, SN7413, SN74LS13 DUAL 4-INPUT

POSITIVE-NAND SCHMITT TRIGGERS

DECEMBER 1983-REVISED MARCH 1988

- Operation from Very Slow Edges
- Improved Line-Receiving Characteristics
- High Noise Immunity

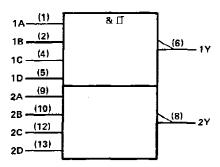
description

Each circuit functions as a 4-input NAND gate, but because of the Schmitt action, it has different input threshold levels for positive (V_{T+}) and for negative going (V_{T-}) signals.

These circuits are temperature-compensated and can be triggered from the slowest of input ramps and still give clean, jitter-free output signals.

The SN5413 and SN54LS13 are characterized for operation over the full military temperature range of ~55°C to 125°C. The SN7413 and SN74LS13 are characterized for operation from 0°C to 70°C.

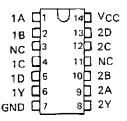
logic symbol†



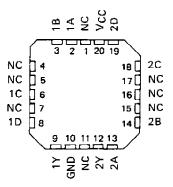
 $^{^\}dagger$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-13.

Pin numbers shown are for D, J, N, and W packages.

SN5413, SN54LS13...J OR W PACKAGE SN7413...N PACKAGE SN74LS13...D OR N PACKAGE (TOP VIEW)

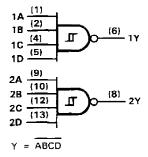


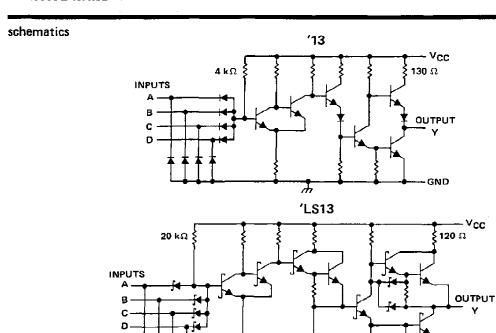
SN54LS13 . . . FK PACKAGE (TOP VIEW)



NC-No internal connection

logic diagram (positive logic)





Resistor values are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC (see Note 1)	7 V
Input voltage: '13	5 .5 V
'LS13	
Operating free-air temperature: \$N54'	– 55°C to 125°C
	0°C to 70°C
Storage temperature range	– 65°C to 150°C

GND

NOTE 1: Voltage values are with respect to network ground terminal.

recommended operating conditions

		SN5413			SN7413			
	MIN	NOM	MAX	MIN	NOM	MAX	UNIT	
VCC Supply voltage	4.5	5	5.5	4,75	5	5.25	V	
IOH High-level output current			- 0.8			- 0.8	mA	
IOL Low-level output current			16			16	mA	
TA Operating free-air temperature	- 55		125	0		70	°C	

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST COND	ITIONS [†]	MIN	түр‡	MAX	UNIT
V _{T+}	V _{CC} = 5 V		1,5	1.7	2	V
∨ _T _	V _{CC} = 5 V		0.6	0.9	1.1	V
Hysteresis (VT+ -VT_)	V _{CC} = 5 V		0.4	0.8		٧
VIK	V _{CC} = MIN, I ₁ = -12 mA				– 1.5	V
Voн	V _{CC} = MIN, V _I = 0.6 V, I _{OH} =	0.8 mA	2.4	3,4		٧
VOL	V _{CC} = MIN, V ₁ = 2 V, I _{OL} = 16	i mA		0.2	0,4	V
IT+	V _{CC} = 5 V, V _I = V _{T+}			- 0.65		mΑ
¹ T-	$V_{CC} = 5 V$, $V_I = V_{T-}$			- 0.85		mA
11	V _{CC} = MAX, V _I = 5.5 V				1	mA
ЦЩ	VCC = MAX, VIH = 2.4 V				40	μА
HL	V _{CC} = MAX, V _{IL} = 0.4 V			- 1	- 1.6	mA
IOS §	V _{CC} = MAX,		- 18		- 55	mΑ
ICCH	V _{CC} = MAX			14	23	mΑ
ICCL	V _{CC} = MAX			20	32	mΑ

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

switching characteristics, VCC = 5 V, TA = 25°C

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
tpLH	Any	Υ	$R_1 = 400 \Omega$, $C_1 = 15 pF$		18	27	ns
tPHL_	,		11 <u>1</u> 100 42, 0 <u>1</u> 10 4		15	22	ns

[‡] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ} \text{ C}$. § Not more than one output should be shorted at a time.

SN54LS13, SN74LS13 **DUAL 4-INPUT** POSITIVE NAND SCHMITT TRIGGERS

recommended operating conditions

	s	N54LS1	54LS13 SN74LS13			TINU	
	MIN	NOM	MAX	MIN	NOM	MAX	UNIT
V _{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	٧
IOH High-level output current			- 0.4			0.4	mA
OL Low-level output current			4			8	mΑ
TA Operating free-air temperature	- 55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	TEST CONDITIONS				N54LS	13		UNIT			
PARAMETER	İ	TEST CON	DITIONS.		MIN	TYP‡	MAX	MIN	TYP‡	MAX	וואטן
V _{T+}	V _{CC} = 5 V				1.4	1,6	1.9	1.4	1.6	1.9	V
V _T _	V _{CC} = 5 V				0,5	0,8	1	0.5	0.8	1	V
Hysteresis (VT+ -VT_)	V _{CC} = 5 V			_	0.4	0.8		0.4	0.8		V
ViK	VCC = MIN.	I _I = - 18 mA					1.5			1.5	V
VOH	V _{CC} = MIN,	V ₁ = 0.5 V,	I _{OH} = − 0,4 m.	A	2.5	3.4		2.7	3.4		V
		V ₁ = 1.9 V		I _{OL} ~ 4 mA		0.25	0.4		0.25	0.4	
VOL	V _{OL} V _{CC} = MIN,			10L = 8 mA					0.35	0.5	'
∤ T+	V _{CC} = 5 V,	V1 = VT+				- 0.14			- 0.14	•	mA
I _T	V _{CC} = 5 V,	V _I = V _T _				- 0.18			- 0.18		mΑ
I _I	V _{CC} = MAX,	V = 7 V					0.1			0.1	mΑ
lн	V _{CC} = MAX,	V _{IH} = 2.7 V					20			20	μА
ll.	V _{CC} = MAX,	V _{IL} = 0.4 V			l		- 0.4			- 0.4	mΑ
los §	V _{CC} = MAX				- 20		- 100	- 20		- 1 0 0	mΑ
‡CCH	V _{CC} = MAX					2.9	6		2,9	6	mΑ
ICCL	VCC = MAX				1	4.1	7		4.1	7	mΑ

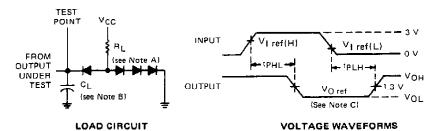
[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

switching characteristics, VCC = 5 V , TA = 25°C

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CON	MIN	TYP	MAX	UNIT	
tpLH	Any	V	$R_1 = 2 k\Omega$,	C ₁ = 15 pF		15	22	ns
tPHL	~'' '	•	11 2 1 2 1 2 1	OL 13 bi		18	27	ns

[‡] All typical values are at V_{CC} = 5 V, T_A = 25°C. § Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second.

PARAMETER MEASUREMENT INFORMATION



NOTES: A. All diodes are 1N3064 or equivalent.

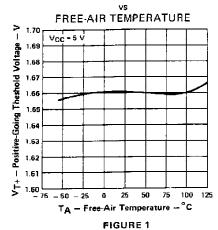
B. C_L includes probe and jig capacitance.

C. Generator characteristics and reference voltages are:

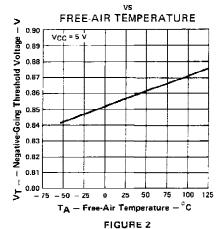
	Generator Characteristics				Reference Voltages				
	Zout	PRR	t _r	tę	Viref(H)	V; ref(L)	V _{O ref}		
SN54'/SN74'	50 Ω	1 MHz	10 ns	10 ns	1,7 V	0.9 V	1.5 V		
SN54LS'/SN74LS'	50 Ω	1 MHz	15 ns	6 ns	1.6 V	0.8 V	1,3 ∨		

TYPICAL CHARACTERISTICS OF '13 CIRCUITS

POSITIVE-GOING THRESHOLD VOLTAGE



NEGATIVE-GOING THRESHOLD VOLTAGE



HYSTERESIS

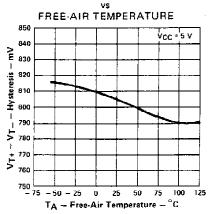
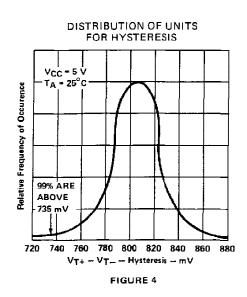
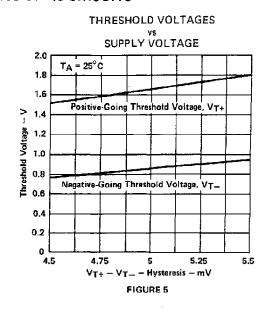


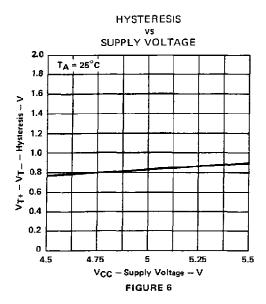
FIGURE 3

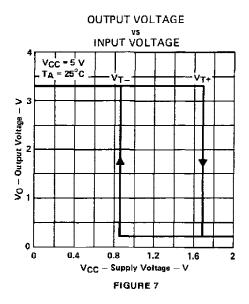
Data for temperatures below 0° C and 70° C and supply voltages below 4.75 V and above 5.25 V are applicable for \$N5413 only.

TYPICAL CHARACTERISTICS OF '13 CIRCUITS





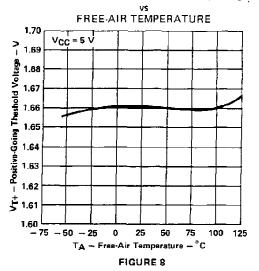




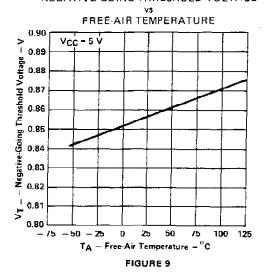
Data for temperatures below 0°C and 70°C and supply voltages below 4.75 V and above 5.25 V are applicable for SN5413 only.

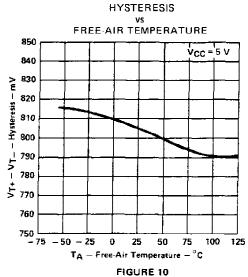
TYPICAL CHARACTERISTICS OF 'LS13 CIRCUITS



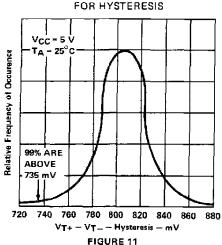


NEGATIVE GOING THRESHOLD VOLTAGE



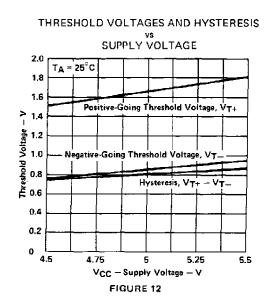


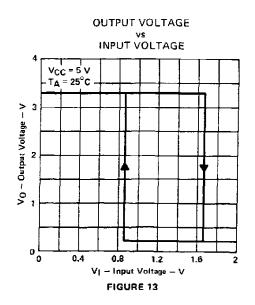
DISTRIBUTION OF UNITS



Data for temperatures below 0°C and above 70°C and supply voltages below 4.75 V and above 5.25 V are applicable for SN54LS13 only.

TYPICAL CHARACTERISTICS OF 'LS13 CIRCUITS

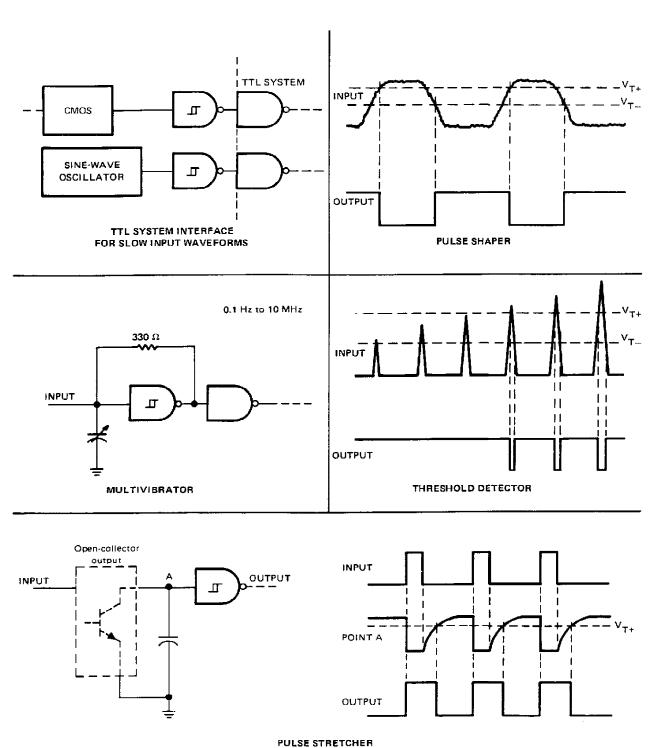




Data for temperatures below 0° C and above 70° C and supply voltages below 4.75 V and above 5.25 V are applicable for SN54LS13 only.



TYPICAL APPLICATION DATA





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